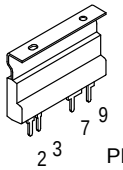
POWER OPTO™ Isolator
2 Amp Zero–Cross Triac Output

This device consists of a gallium arsenide infrared emitting diode optically coupled to a zero–cross triac driver circuit and a power triac. It is capable of driving a load of up to 2 amps (rms) directly, on line voltages from 20 to 280 volts ac (rms).

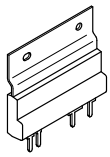
- Provides Normally Open Solid State AC Output with 2 Amp Rating
- 70 Amp Single Cycle Surge Capability
- Zero–Voltage Turn–on and Zero–Current Turn–off
- High Input–Output Isolation of 3750 vac (rms)
- Static dv/dt Rating of 400 Volts/µs Guaranteed
- 2 Amp Pilot Duty Rating Per UL508 ¶117 (Overload Test) and ¶118 (Endurance Test) [File No. 129224]
- CSA Approved [File No. CA77170–1].
- SEMKO Approved Certificate #9507228
- Exceeds NEMA 2–230 and IEEE472 Noise Immunity Test Requirements (See Fig.14)

MOC2A60-10
MOC2A60-5*
***Motorola Preferred Device**

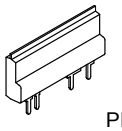
OPTOISOLATOR
2 AMP ZERO CROSS
TRIAC OUTPUT
600 VOLTS



CASE 417–02
Style 2
PLASTIC PACKAGE



CASE 417A–02
Style 1
PLASTIC PACKAGE



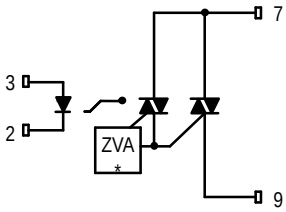
CASE 417B–01
Style 1
PLASTIC PACKAGE

DEVICE RATINGS (T_A = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
INPUT LED			
Forward Current — Maximum Continuous	I_F	50	mA
Forward Current — Maximum Peak (PW = 100µs, 120 pps)	$I_{F(pk)}$	1.0	A
Reverse Voltage — Maximum	V_R	6.0	V
OUTPUT TRIAC			
Output Terminal Voltage — Maximum Transient (1)	V_{DRM}	600	V(pk)
Operating Voltage Range — Maximum Continuous (f = 47 – 63 Hz)	V_T	20 to 280	Vac(rms)
On–State Current Range (Free Air, Power Factor ≥ 0.3)	I_T(rms)	0.03 to 2.0	A
Non–Repetitive Single Cycle Surge Current — Maximum Peak (t = 16.7 ms)	I_{TSM}	70	A
Main Terminal Fusing Current (t = 8.3 ms)	I^2T	26	A^2sec
Load Power Factor Range	PF	0.3 to 1.0	—
Junction Temperature Range	T_J	– 40 to 125	°C
TOTAL DEVICE			
Input–Output Isolation Voltage — Maximum(2) 47 – 63 Hz, 1 sec Duration	V_{ISO}	3750	Vac(rms)
Thermal Resistance — Power Triac Junction to Case (See Fig. 15)	$R_{\theta JC}$	8.0	°C/W
Ambient Operating Temperature Range	T_{oper}	– 40 to +100	°C
Storage Temperature Range	T_{stg}	– 40 to +150	°C
Lead Soldering Temperature — Maximum (1/16″ from Case, 10 sec Duration)	T_L	260	°C

1. Test voltages must be applied within dv/dt rating.
2. Input–Output isolation voltage, V_{ISO}, is an internal device dielectric breakdown rating. For this test, pins 2, 3 and the heat tab are common, and pins 7 and 9 are common.

DEVICE SCHEMATIC



* Zero Voltage Activate Circuit

1, 4, 5, 6, 8. NO PIN
2. LED CATHODE
3. LED ANODE
7. MAIN TERMINAL 2
9. MAIN TERMINAL 1

POWER OPTO is a trademark of Motorola, Inc.

Preferred devices are Motorola recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Typ	Max	Unit
INPUT LED						
Forward Voltage (I_F = 10 mA)		V_F	1.00	1.17	1.50	V
Reverse Leakage Current (V_R = 6.0 V)		I_R	—	1.0	100	µA
Capacitance		C	—	18	—	pF
OUTPUT TRIAC						
Off–State Leakage, Either Direction (I_F = 0, V_{DRM} = 600 V)		I_{DRM}	—	0.25	10	µA
Critical Rate of Rise of Off–State Voltage (Static) V_{in} = 400 vac(pk)) (1)(2)		dv/dt(s)	400	—	—	V/µs
Holding Current, Either Direction (I_F = 0, V_D = 12 V, I_T = 200 mA)		I_H	—	10	—	mA
COUPLED						
LED Trigger Current Required to Latch Output Either Direction (Main Terminal Voltage = 2.0 V)(3)(4)	MOC2A60–10	I_{FT}(on)	—	7.0	10	mA
	MOC2A60–5	I_{FT}(on)	—	3.5	5.0	mA
On–State Voltage, Either Direction (I_F = Rated I_{FT}(on), I_{TM} = 2.0 A)		V_{TM}	—	0.96	1.3	V
Inhibit Voltage, Either Direction (I_F = Rated I_{FT}(on))(5) (Main Terminal Voltage above which device will not trigger)		V_{INH}	—	8.0	10	V
Commutating dv/dt (Rated V_{DRM}, I_T = 30 mA – 2.0 A(rms), T_A = – 40 ± 100°C, f = 60 Hz)(2)		dv/dt (c)	5.0	—	—	V/µS
Common–mode Input–Output dv/dt(2)		dv/dt(cm)	—	40,000	—	V/µS
Input–Output Capacitance (V = 0, f = 1.0 MHz)		C_{ISO}	—	1.3	—	pF
Isolation Resistance ($V_{I–O}$ = 500 V)		R_{ISO}	10^{12}	10^{14}	—	Ω

1. Per EIA/NARM standard RS–443, with V_P = 200 V, which is the instantaneous peak of the maximum operating voltage.
2. Additional dv/dt information, including test methods, can be found in Motorola applications note AN1048/D, Figure 43.
3. All devices are guaranteed to trigger at an I_F value less than or equal to the max I_{FT}. Therefore, the recommended operating I_F lies between the device's maximum I_{FT}(on) limit and the Maximum Rating of 50 mA.
4. Current–limiting resistor required in series with LED.
5. Also known as "Zero Voltage Turn–On."

TYPICAL CHARACTERISTICS

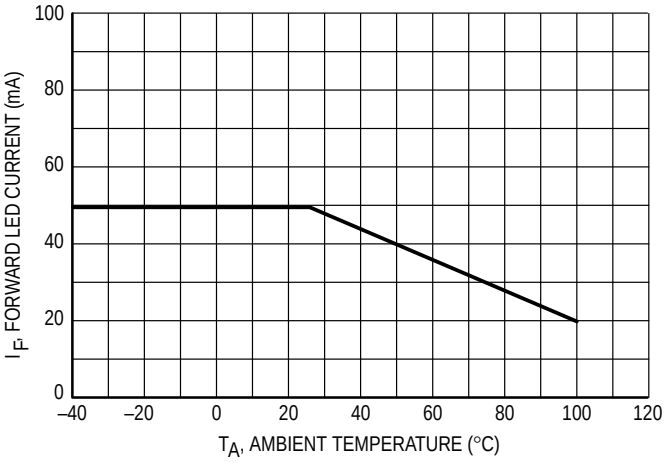


Figure 1. Maximum Allowable Forward LED Current versus Ambient Temperature

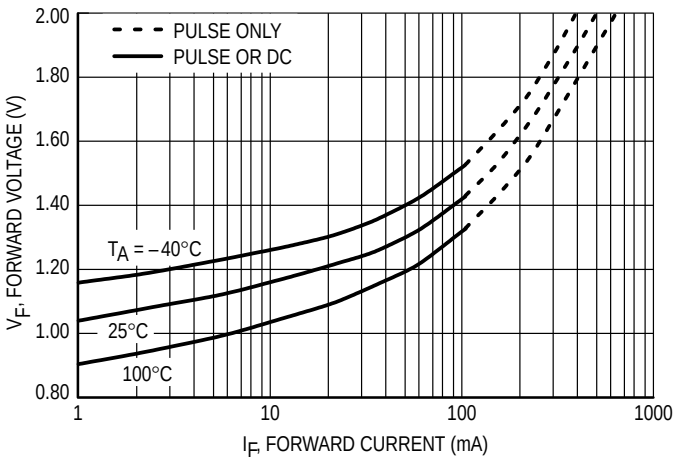


Figure 2. LED Forward Voltage versus LED Forward Current

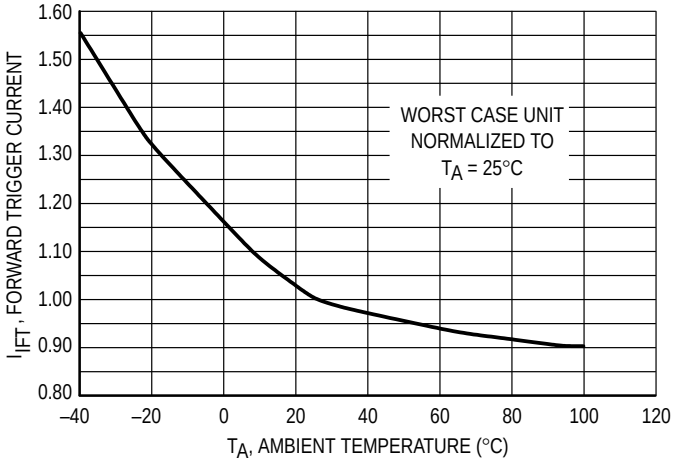


Figure 3. Forward LED Trigger Current versus Ambient Temperature

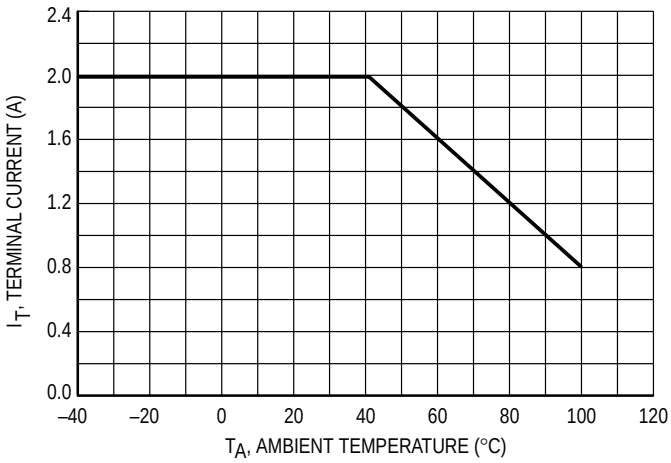


Figure 4. Maximum Allowable On–State RMS Output Current (Free Air) versus Ambient Temperature

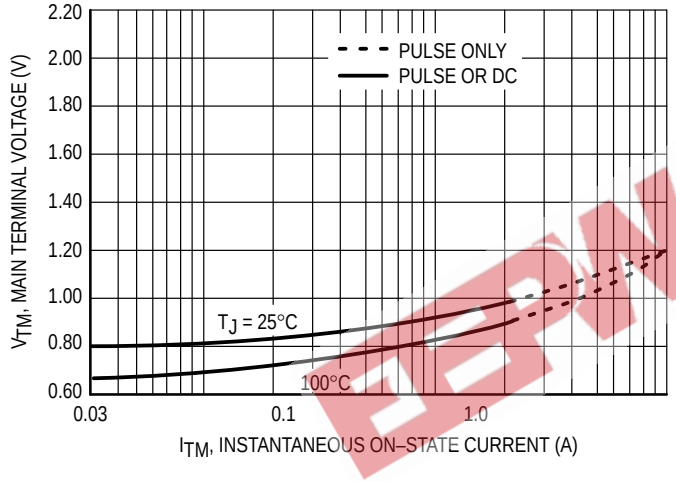


Figure 5. On–State Voltage Drop versus Output Terminal Current

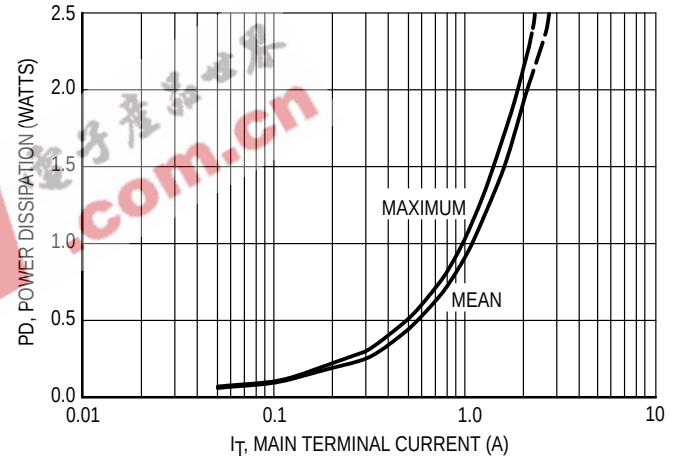


Figure 6. Power Dissipation versus Main Terminal Current

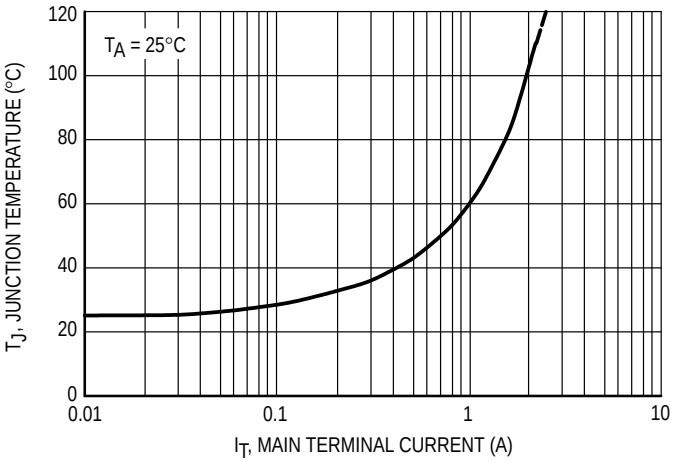


Figure 7. Junction Temperature versus Main Terminal RMS Current (Free Air)

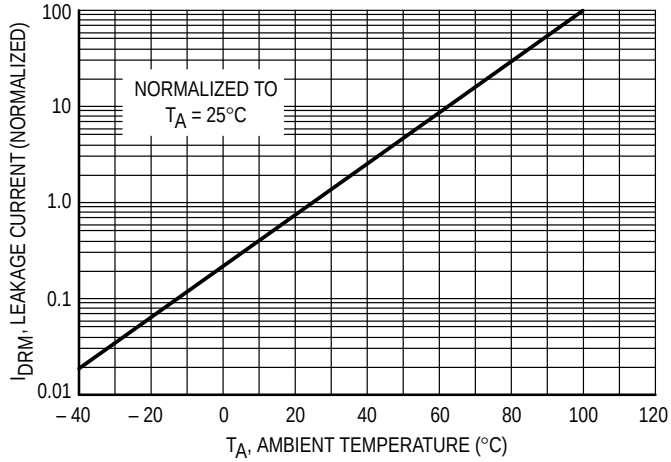


Figure 8. Leakage with LED Off versus Ambient Temperature

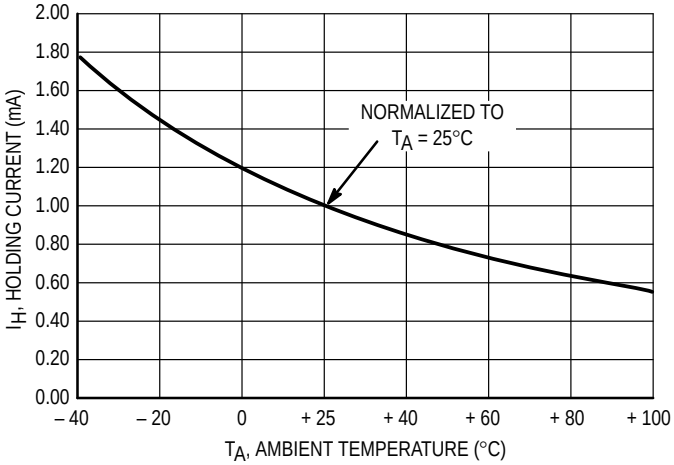


Figure 9. Holding Current versus Ambient Temperature

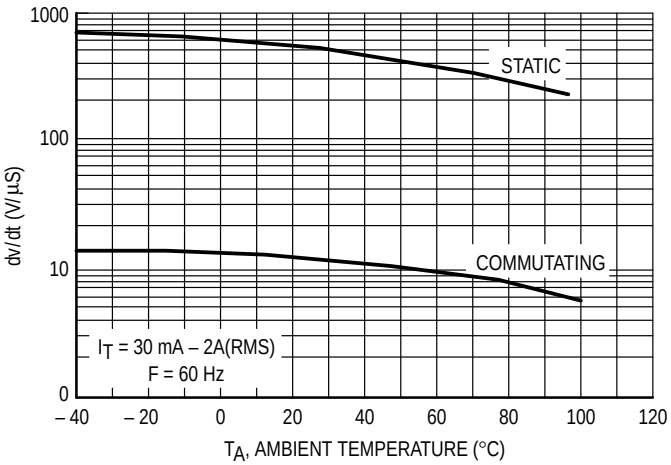


Figure 10. dv/dt versus Ambient Temperature

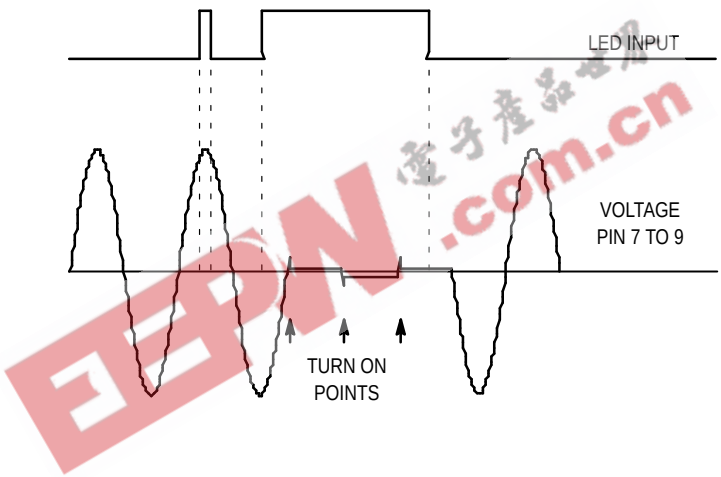


Figure 11. Operating Waveforms

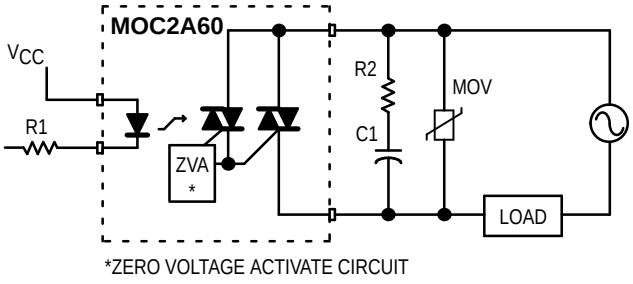


Figure 12. Typical Application Circuit

Select the value of R1 according to the following formulas:

[1] $R1 = (V_{CC} - V_F) / \text{Max. } I_{FT} \text{ (on) per spec.}$

[2] $R1 = (V_{CC} - V_F) / 0.050$

Typical values for C1 and R2 are 0.01 µF and 39 Ω, respectively. You may adjust these values for specific applications. The maximum recommended value of C1 is 0.022 µF. See application note AN1048 for additional information on component values.

The MOV may or may not be needed depending upon the characteristics of the applied ac line voltage. For applications where line spikes may exceed the 600 V rating of the MOC2A60, an MOV is required.

Use care to maintain the minimum spacings as shown. Safety and regulatory requirements dictate a minimum of 8.0 mm between the closest points between input and output conducting paths, Pins 3 and 7. Also, 0.070 inches distance is required between the two output Pins, 7 and 9.

Keep pad sizes on Pins 7 and 9 as large as possible for optimal performance.

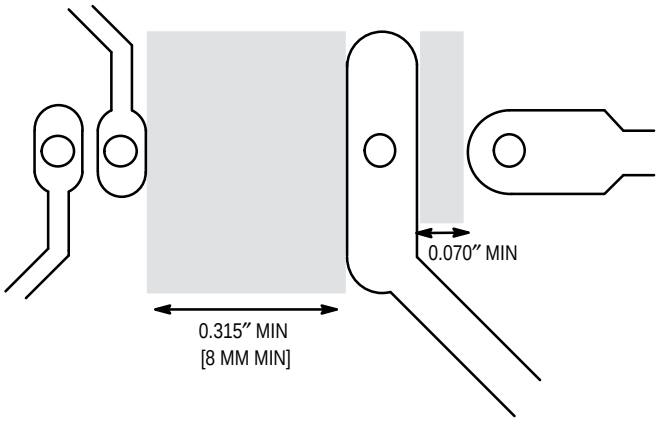


Figure 13. PC Board Layout Recommendations

Each device, when installed in the circuit shown in Figure 14, shall be capable of passing the following conducted noise tests:

- IEEE 472 (2.5 KV)
- Lamp Dimmer (NEMA Part DC33, § 3.4.2.1)
- NEMA ICS 2–230.45 Showering Arc
- MIL–STD–461A CS01, CS02 and CS06

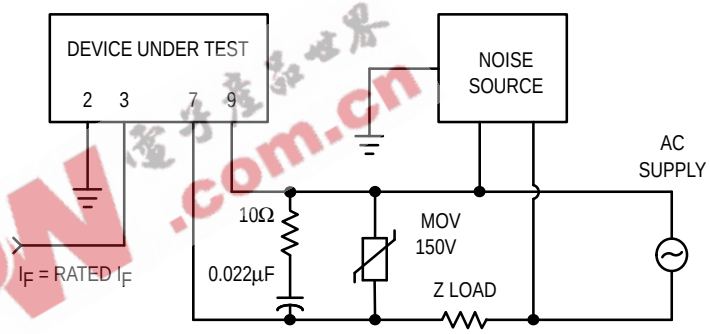
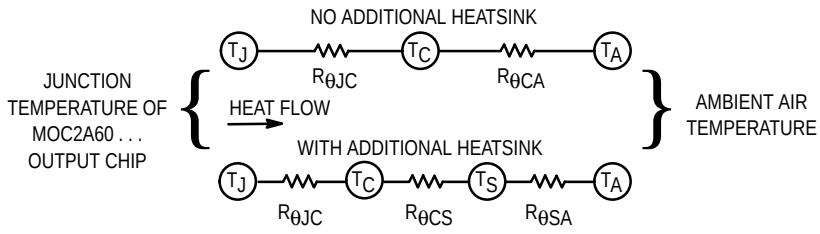


Figure 14. Test Circuit for Conducted Noise Tests



Terms in the model signify:

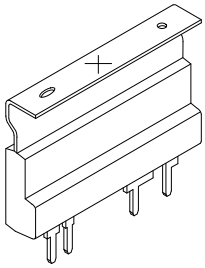
T_A = Ambient temperature
T_S = Optional additional heat sink temperature
T_C = Case temperature
T_J = Junction temperature
P_D = Power dissipation

$R_{\theta SA}$ = Thermal resistance, heat sink to ambient
$R_{\theta CA}$ = Thermal resistance, case to ambient
$R_{\theta CS}$ = Thermal resistance, heat sink to case
$R_{\theta JC}$ = Thermal resistance, junction to case

Values for thermal resistance components are: $R_{\theta CA}$ = 36°C/W/in maximum
$R_{\theta JC}$ = 8.0°C/W maximum

The design of any additional heatsink will determine the values of $R_{\theta SA}$ and $R_{\theta CS}$.

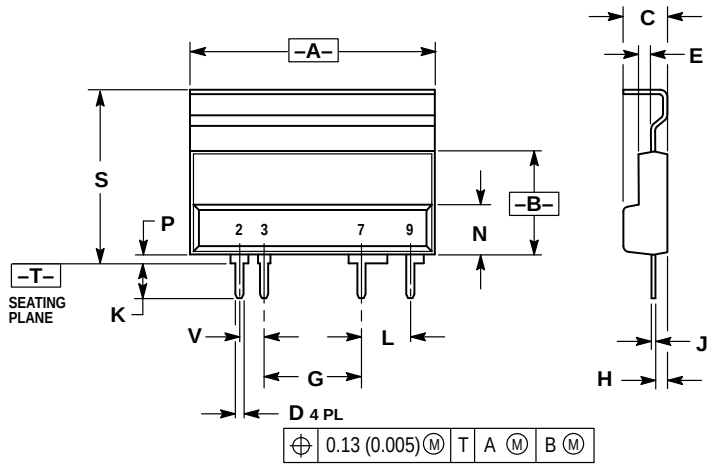
$T_C - T_A = P_D (R_{\theta CA})$
$= P_D (R_{\theta JC}) + R_{\theta SA})$, where P_D = Power Dissipation in Watts.



Thermal measurements of $R_{\theta JC}$ are referenced to the point on the heat tab indicated with an 'X'. Measurements should be taken with device orientated along its vertical axis.

Figure 15. Approximate Thermal Circuit Model

PACKAGE DIMENSIONS



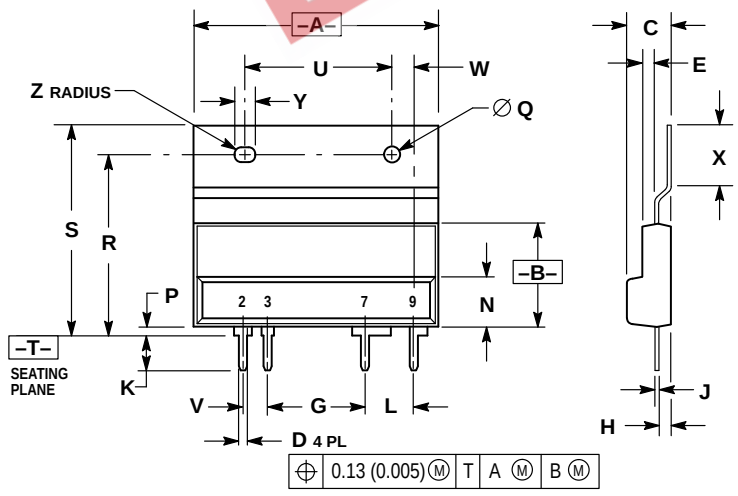
NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.965	1.005	24.51	25.53
B	0.416	0.436	10.57	11.07
C	0.170	0.190	4.32	4.83
D	0.025	0.035	0.64	0.89
E	0.040	0.060	1.02	1.52
G	0.400 BSC		10.16 BSC	
H	0.040	0.060	1.02	1.52
J	0.012	0.018	0.30	0.46
K	0.134	0.154	3.40	3.91
L	0.200 BSC		5.08 BSC	
N	0.190	0.210	4.83	5.33
P	0.023	0.043	0.58	1.09
S	0.695	0.715	17.65	18.16
V	0.100 BSC		2.54 BSC	

STYLE 2:
PIN 2. LED CATHODE
3. LED ANODE
7. TRIAC MT
9. TRIAC MT

CASE 417–02
PLASTIC
STANDARD HEAT TAB
ISSUE C

ORDER "F" SUFFIX
HEAT TAB OPTION
(EX: MOC2A60–10F)



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

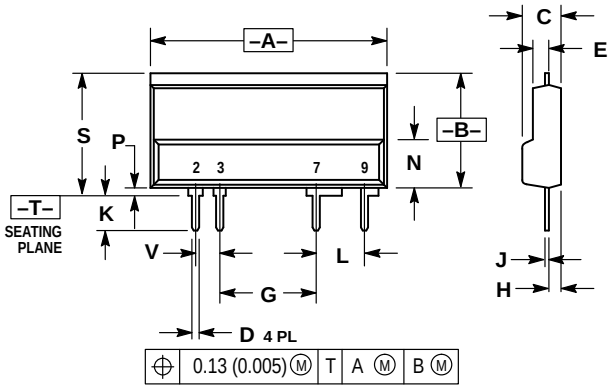
	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.965	1.005	24.51	25.53
B	0.416	0.436	10.57	11.07
C	0.170	0.190	4.32	4.83
D	0.025	0.035	0.64	0.89
E	0.040	0.060	1.02	1.52
G	0.400 BSC		10.16 BSC	
H	0.040	0.060	1.02	1.52
J	0.012	0.018	0.30	0.46
K	0.134	0.154	3.40	3.91
L	0.200 BSC		5.08 BSC	
N	0.190	0.210	4.83	5.33
P	0.023	0.043	0.58	1.09
Q	0.057	0.067	1.45	1.70
R	0.734	0.754	18.64	19.15
S	0.840	0.870	21.34	22.10
U	0.593	0.613	15.06	15.57
V	0.100 BSC		2.54 BSC	
W	0.074	0.094	1.88	2.39
X	0.265	0.295	6.73	7.49
Y	0.079	0.089	2.01	2.26
Z	0.026	0.036	0.66	0.91

STYLE 1:
PIN 2. LED CATHODE
3. LED ANODE
7. TRIAC MT
9. TRIAC MT

CASE 417A–02
PLASTIC
FLUSH MOUNT HEAT TAB
ISSUE A

PACKAGE DIMENSIONS — CONTINUED

ORDER “C” SUFFIX
HEAT TAB OPTION
(EX: MOC2A60–10C)



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.965	1.005	24.51	25.53
B	0.416	0.436	10.57	11.07
C	0.170	0.190	4.32	4.83
D	0.025	0.035	0.64	0.89
E	0.040	0.060	1.02	1.52
G	0.400 BSC		10.16 BSC	
H	0.040	0.060	1.02	1.52
J	0.012	0.060	0.30	0.46
K	0.134	0.154	3.40	3.91
L	0.200 BSC		5.08 BSC	
N	0.190	0.210	4.83	5.33
P	0.023	0.043	0.58	1.09
S	0.439	0.529	11.15	13.44
V	0.100 BSC		2.54 BSC	

STYLE 1:
PIN 2. LED CATHODE
3. LED ANODE
7. TRIAC MT
9. TRIAC MT

CASE 417B–01
PLASTIC
CUT HEAT TAB
ISSUE O

How to reach us:
USA / EUROPE: Motorola Literature Distribution;
P.O. Box 20912; Phoenix, Arizona 85036. 1–800–441–2447

MFAX: RMFAX0@email.sps.mot.com – TOUCHTONE (602) 244–6609
INTERNET: http://Design–NET.com

JAPAN: Nippon Motorola Ltd.; Tatsumi–SPD–JLDC, Toshikatsu Otsuki,
6F Seibu–Butsuryu–Center, 3–14–2 Tatsumi Koto–Ku, Tokyo 135, Japan. 03–3521–8315

HONG KONG: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park,
51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852–26629298